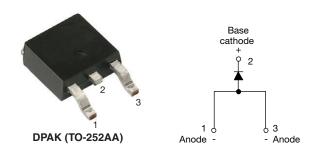


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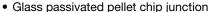
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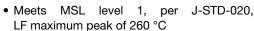
## Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



| PRIMARY CHARACTERISTICS          |                |  |  |  |  |  |
|----------------------------------|----------------|--|--|--|--|--|
| I <sub>F(AV)</sub> 8 A           |                |  |  |  |  |  |
| $V_{R}$                          | 1000 V, 1200 V |  |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 1.3 V          |  |  |  |  |  |
| I <sub>FSM</sub>                 | 150 A          |  |  |  |  |  |
| t <sub>rr</sub>                  | 80 ns          |  |  |  |  |  |
| T <sub>J</sub> max.              | 150 °C         |  |  |  |  |  |
| Snap factor                      | 0.6            |  |  |  |  |  |
| Package DPAK (TO-252AA)          |                |  |  |  |  |  |
| Circuit configuration            | Single         |  |  |  |  |  |

### **FEATURES**











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### **APPLICATIONS**

- Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

### **DESCRIPTION**

The VS-8EWF..S-M3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

| MAJOR RATINGS AND CHARACTERISTICS |                             |             |    |  |  |  |  |
|-----------------------------------|-----------------------------|-------------|----|--|--|--|--|
| SYMBOL                            | OL CHARACTERISTICS VALUES U |             |    |  |  |  |  |
| I <sub>F(AV)</sub>                | Sinusoidal waveform         | 8           | A  |  |  |  |  |
| V <sub>RRM</sub>                  |                             | 1000/1200   | V  |  |  |  |  |
| I <sub>FSM</sub>                  |                             | 150         | A  |  |  |  |  |
| V <sub>F</sub>                    | 8 A, T <sub>J</sub> = 25 °C | 1.3         | V  |  |  |  |  |
| t <sub>rr</sub>                   | 1 A, 100 A/µs               | 80          | ns |  |  |  |  |
| T <sub>J</sub>                    | Range                       | -40 to +150 | °C |  |  |  |  |

| VOLTAGE RATINGS |  |                                     |   |  |  |  |  |
|-----------------|--|-------------------------------------|---|--|--|--|--|
| PART NUMBER     | V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | I <sub>RRM</sub><br>AT 150 °C<br>mA |   |  |  |  |  |
| VS-8EWF10S-M3   | 1000   | 1100                                | 4 |  |  |  |  |
| VS-8EWF12S-M3   | 1200   | 1300                                | 4 |  |  |  |  |

| ABSOLUTE MAXIMUM RATINGS                             |                    |  |        |                   |  |  |
|--|--------------------|--|--------|-------------------|--|--|
| PARAMETER  | SYMBOL             | TEST CONDITIONS  | VALUES | UNITS             |  |  |
| Maximum average forward current                      | I <sub>F(AV)</sub> | T <sub>C</sub> = 96 °C, 180° conduction half sine wave | 8      |                   |  |  |
| Maximum peak one cycle                               |                    | 10 ms sine pulse, rated V <sub>RRM</sub> applied       | 125    | Α                 |  |  |
| non-repetitive surge current                         | I <sub>FSM</sub>   | 10 ms sine pulse, no voltage reapplied                 | 150    |                   |  |  |
| Maximum I <sup>2</sup> t for fusing I <sup>2</sup> t |                    | 10 ms sine pulse, rated V <sub>RRM</sub> applied       | 78     | A <sup>2</sup> s  |  |  |
| Maximum I <sup>2</sup> t for fusing                  | ı-t                | 10 ms sine pulse, no voltage reapplied                 | 110    | A-S               |  |  |
| Maximum I <sup>2</sup> √t for fusing                 | I <sup>2</sup> √t  | t = 0.1 ms to 10 ms, no voltage reapplied              | 1100   | A <sup>2</sup> √s |  |  |



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| ELECTRICAL SPECIFICATIONS       |                    |                                    |   |      |      |  |  |
|---------------------------------|--------------------|------------------------------------|---|------|------|--|--|
| PARAMETER                       | SYMBOL             | SYMBOL TEST CONDITIONS VALUES UNIT |   |      |      |  |  |
| Maximum forward voltage drop    | $V_{FM}$           | 8 A, T <sub>J</sub> = 25 °C        |   | 1.3  | V    |  |  |
| Forward slope resistance        | r <sub>t</sub>     | T <sub>.1</sub> = 150 °C           |   | 25.6 | mΩ   |  |  |
| Threshold voltage               | V <sub>F(TO)</sub> | 1J = 150 C                         |   | 0.93 | V    |  |  |
| Maximum reverse leakage current |                    | T <sub>J</sub> = 25 °C             | V - Patad V                             | 0.1  | mA   |  |  |
| Maximum reverse leakage current | I <sub>RM</sub>    | T <sub>J</sub> = 150 °C            | V <sub>R</sub> = Rated V <sub>RRM</sub> | 4    | IIIA |  |  |

| RECOVERY CHARACTERISTICS |                 |                                     |        |       |   |  |
|--------------------------|-----------------|-------------------------------------|--------|-------|---|--|
| PARAMETER                | SYMBOL          | TEST CONDITIONS                     | VALUES | UNITS | · •   |  |
| Reverse recovery time    | t <sub>rr</sub> | I <sub>F</sub> at 8 A <sub>pk</sub> | 270    | ns    | I <sub>FM</sub>   |  |
| Reverse recovery current | I <sub>rr</sub> | 25 A/μs                             | 4.2    | А     | $\left \begin{array}{c} \left \begin{array}{c} \overline{t_{rr}} \\ \overline{t_a} & \overline{t_h} \end{array}\right  \right $ |  |
| Reverse recovery charge  | Q <sub>rr</sub> | T <sub>J</sub> = 25 °C              | 1      | μC    | di di Q   |  |
| Snap factor              | S               |                                     | 0.6    |       | l I I I I I I I I I I I I I I I I I I I   |  |

| THERMAL - MECHANICAL SPECIFICATIONS                         |                                   |                            |             |       |  |  |
|---|-----------------------------------|----------------------------|-------------|-------|--|--|
| PARAMETER   | SYMBOL                            | TEST CONDITIONS            | VALUES      | UNITS |  |  |
| Maximum junction and storage temperature range              | T <sub>J</sub> , T <sub>Stg</sub> |                            | -40 to +150 | °C    |  |  |
| Maximum thermal resistance, junction to case                | R <sub>thJC</sub>                 | DC operation               | 2.5         | °C/W  |  |  |
| Typical thermal resistance, junction to ambient (PCB mount) | R <sub>thJA</sub> (1)             |                            | 50          | C/VV  |  |  |
| Approximate weight  |                                   |                            | 1           | g     |  |  |
| Approximate weight  |                                   |                            | 0.03        | oz.   |  |  |
| Marking davise  |                                   | Consistua DDAK (TO 252AA)  | 8EWF        | -10S  |  |  |
| Marking device  |                                   | Case style DPAK (TO-252AA) | 8EWF12S     |       |  |  |

### Note

<sup>(1)</sup> When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

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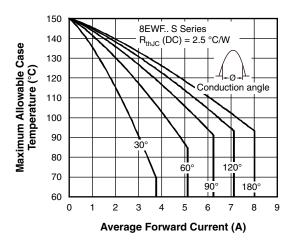


Fig. 1 - Current Rating Characteristics

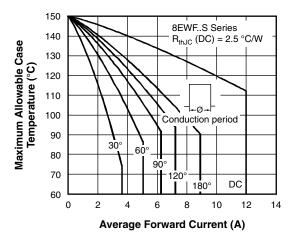


Fig. 2 - Current Rating Characteristics

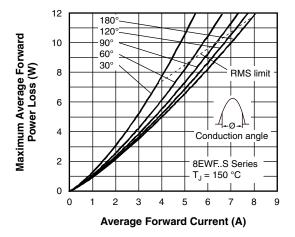


Fig. 3 - Forward Power Loss Characteristics

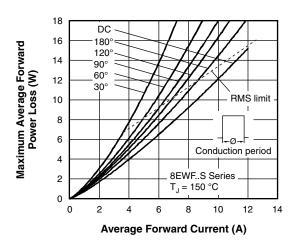


Fig. 4 - Forward Power Loss Characteristics

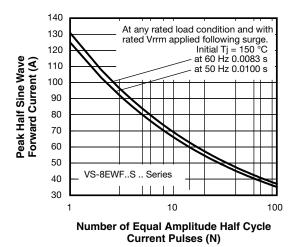


Fig. 5 - Maximum Non-Repetitive Surge Current

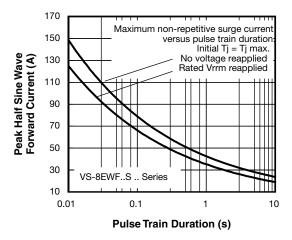


Fig. 6 - Maximum Non-Repetitive Surge Current



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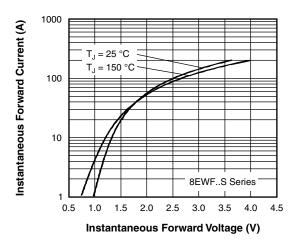


Fig. 7 - Forward Voltage Drop Characteristics

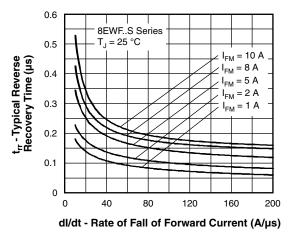


Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

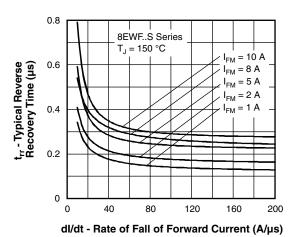


Fig. 9 - Recovery Time Characteristics,  $T_J = 150 \, ^{\circ}\text{C}$ 

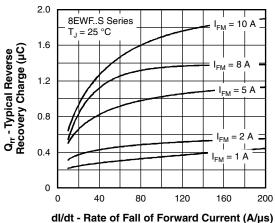


Fig. 10 - Recovery Charge Characteristics, T<sub>,I</sub> = 25 °C

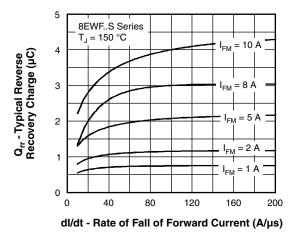


Fig. 11 - Recovery Charge Characteristics, T<sub>J</sub> = 150 °C

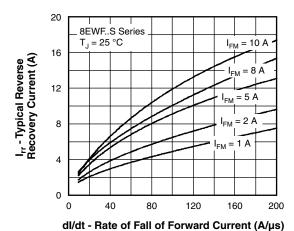
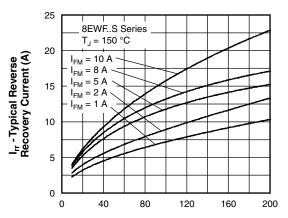


Fig. 12 - Recovery Current Characteristics, T<sub>J</sub> = 25 °C

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dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

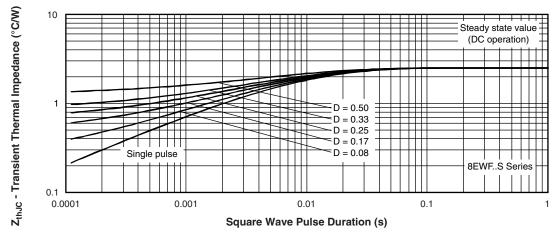
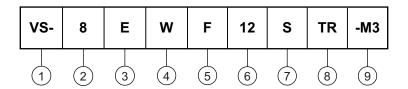


Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics

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### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

3 - Circuit configuration:

E = single diode

4 - Package:

W = D-PAK

5 - Type of silicon:

F = fast soft recovery rectifier

6 - Voltage code x 100 = V<sub>RRM</sub> — 10 = 1000 V 12 = 1200 V

7 - S = surface mountable

Fig. 6 TR = tape and reel

• TRR = tape and reel (right oriented)

• TRL = tape and reel (left oriented)

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) |                  |                        |                          |  |  |  |  |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|--|
| PREFERRED P/N                  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION    |  |  |  |  |
| VS-8EWF10S-M3                  | 75               | 3000                   | Antistatic plastic tubes |  |  |  |  |
| VS-8EWF10STR-M3                | 2000             | 2000                   | 13" diameter reel        |  |  |  |  |
| VS-8EWF10STRL-M3               | 3000             | 3000                   | 13" diameter reel        |  |  |  |  |
| VS-8EWF10STRR-M3               | 3000             | 3000                   | 13" diameter reel        |  |  |  |  |
| VS-8EWF12S-M3                  | 75               | 3000                   | Antistatic plastic tubes |  |  |  |  |
| VS-8EWF12STR-M3                | 2000             | 2000                   | 13" diameter reel        |  |  |  |  |
| VS-8EWF12STRL-M3               | 3000             | 3000                   | 13" diameter reel        |  |  |  |  |
| VS-8EWF12STRR-M3               | 3000             | 3000                   | 13" diameter reel        |  |  |  |  |

| LINKS TO RELATED DOCUMENTS                 |                          |  |  |  |  |
|--|--------------------------|--|--|--|--|
| Dimensions <u>www.vishay.com/doc?95627</u> |                          |  |  |  |  |
| Part marking information                   | www.vishay.com/doc?95176 |  |  |  |  |
| Packaging information                      | www.vishay.com/doc?95033 |  |  |  |  |
| SPICE model                                | www.vishay.com/doc?97057 |  |  |  |  |



## Vishay Semiconductors

# D-PAK (TO-252AA) "M"

### **DIMENSIONS** in millimeters and inches



| SYMBOL   | MILLIN | IETERS | INCHES |       | NOTES |
|----------|--------|--------|--------|-------|-------|
| STINIBOL | MIN.   | MAX.   | MIN.   | MAX.  | NOTES |
| Α        | 2.18   | 2.39   | 0.086  | 0.094 |       |
| A1       | -      | 0.13   | -      | 0.005 |       |
| b        | 0.64   | 0.89   | 0.025  | 0.035 |       |
| b2       | 0.76   | 1.14   | 0.030  | 0.045 |       |
| b3       | 4.95   | 5.46   | 0.195  | 0.215 | 3     |
| С        | 0.46   | 0.61   | 0.018  | 0.024 |       |
| c2       | 0.46   | 0.89   | 0.018  | 0.035 |       |
| D        | 5.97   | 6.22   | 0.235  | 0.245 | 5     |
| D1       | 5.21   | -      | 0.205  | 1     | 3     |
| Е        | 6.35   | 6.73   | 0.250  | 0.265 | 5     |
| E1       | 4.32   | -      | 0.170  | -     | 3     |

| SYMBOL  | MILLIN | IETERS   | INC       | HES   | NOTES |
|---------|--------|----------|-----------|-------|-------|
| OTWIDOL | MIN.   | MAX.     | MIN.      | MAX.  | NOTES |
| е       | 2.29   | BSC      | 0.090     | BSC   |       |
| Н       | 9.40   | 10.41    | 0.370     | 0.410 |       |
| L       | 1.40   | 1.78     | 0.055     | 0.070 |       |
| L1      | 2.74   | 2.74 BSC |           | REF.  |       |
| L2      | 0.51   | BSC      | 0.020 BSC |       |       |
| L3      | 0.89   | 1.27     | 0.035     | 0.050 | 3     |
| L4      | -      | 1.02     | -         | 0.040 |       |
| L5      | 1.14   | 1.52     | 0.045     | 0.060 | 2     |
| Ø       | 0°     | 10°      | 0°        | 10°   |       |
| Ø1      | 0°     | 15°      | 0°        | 15°   |       |
| Ø2      | 25°    | 35°      | 25°       | 35°   |       |

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA



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